Mini-symposium

Contemporary approaches to atomic scale crystal growth simulations

25 February 2016

LOCATION: Institute of Physics (IP), Polish Academy of Sciences (PAS) in Warsaw, room D

ORGANIZERS:

Magdalena Załuska-Kotur and Filip Krzyżewski

Institute of Physics, Polish Academy of Sciences

Vesselin Tonchev

Institute of Physical Chemistry, Bulgarian Academy of Sciences

James F. Lutsko

Center for Nonlinear Phenomena and Complex Systems, Université Libre de Bruxelle

Program

9:30 Opening Welcome note by the organizers

9:35 James F. Lutsko (CNPCS, ULB): *The effect of thermal fluctuations on impurity-driven crystal growth cessation.*

10:15 Łukasz A. Turski (Center for Theoretical Physics, PAS): *Crystal growth as seen from dinosaur view*

10.45 Anna Hoser (Chemical Faculty, Warsaw University): *The role of the lattice energy calculations in the crystal growth study*

11:15 Ioana Sovago (**Chemical Faculty, Warsaw University**)**:** *Aspirin crystallization*

11.45 Magdalena Załuska-Kotur (IP, PAS): *Cellular automaton based atomistic scale model for fast and effective modelling of unstable vicinal crystal growth.*

Coffee break

12:30 Stanisław Krukowski (Institute for High Pressure Physics, PAS): *Electronic contribution to energy of adsorption on semiconductor surfaces - consequences to crystal growth mechanism*

13:00 Paweł Strąk (Institute for High Pressure Physics, PAS): *Polar Al-terminated AlN (0001) surface in the presence of nitrogen*

13:30 Filip Krzyżewski (IP-PAS): *Various surface morphologies observed during simulations of GaN crystals growth*

Lunch break

14:40 Vesselin Tonchev (IPC-BAS): *Diffusion-limited vs. kinetics-limited: What we learned from the Sato-Uwaha model of unstable vicinal crystal growth*

15:10 Marcin Mińkowski (IP, PAS): *Self-organizing structures in immiscible crystals*

15:30 Roundtable discussion: Collaboration prospective in the EU context